

School of Electrical and Electronic Engineering



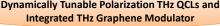
COEB - Centre for OptoElectronics and Biophotonics

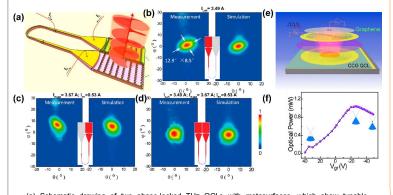
Mid-IR and Terahertz Science and Technologies

Research Interests

We are going to investigate the fundamental properties (optical and electrical) of semiconductor (quantum cascade lasers) and nanophotonic devices (such as graphene optoelectronic devices) in the infrared frequency regimes (including mid-IR (~3-30 µm) and terahertz (~60-300 µm)) to improve their performance. Exploration of their broad potential applications is also one of the key focuses.

Quantum Cascade Lasers High Power Mid-IR QCLs and Broadly Localized Multimode Random QCLs **Tunable Mid-IR QCLs** 2.37 kA/cm 2.13 kA/cm 1.99 kA/cm (a.u.) (b) (c) 1.80 kA/cm (h) (c) 4.2 4.4 4.6 4.8 5.0 5.2 5.5 Wavelength (μm) (a) 3D schematic diagram of a surface emitting random QCL. (b) SEM images of the quantum cascade pillars at an oblique and (c) the surface of the QCL device. (d) Typical localized mode. (e) (a) 3D schematic of Talbot-cavity QCL.(b-c) SEM images of the Talbot cavity (b) and output facet of the Emission spectra of a random QCL at different pumping current densities QCL array (c). (d) laser spectrum of Talbot-cavity QCL. (e-g) 3D schematic diagram, optical microscopy and SEM of the slot-QCLs. (h) Tunable single-mode spectra of slot-QCLs. NanoPhotonics **Dynamically Tunable Polarization THz QCLs and** High Performance Graphene Lateral BP pn junction for PDs Nanoribbon Photodetector





(a) Schematic drawing of two phase-locked THz QCLs with metasurfaces, which show tunable polarization of THz frequency radiation. (b-d) Measured and simulated far-field patterns of the device ith different pumping conditions.(e) Schematic illustration of QCL integrated graphene modulator. (f) V_G dependence of the output power of the concentric-circular grating QCL with the graphene

Project Members

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Mid-IR Extreme UV Terahertz Ultraviolet 1 mm 100 μm 10 um 100 nm Wavelength λ (m) **Broadband PDs** Based on Transition metal dichalcogenides

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